

T-79-08

IR9022/IR9022N Low Power Dual Operational Amplifier

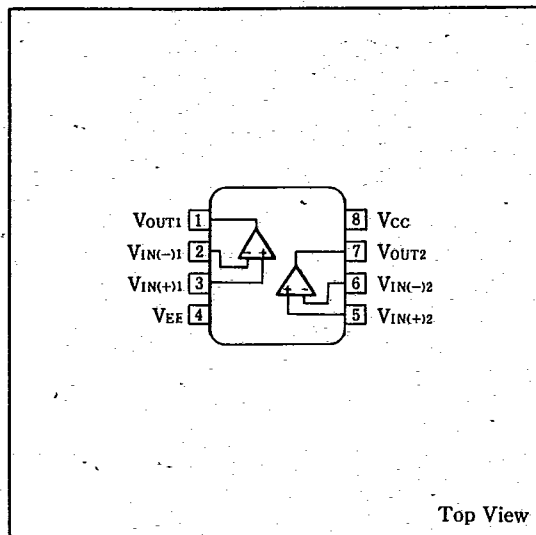
Description

The IR9022/IR9022N is a dual low power operational amplifier for use in variety of low power applications including battery-operated circuits.

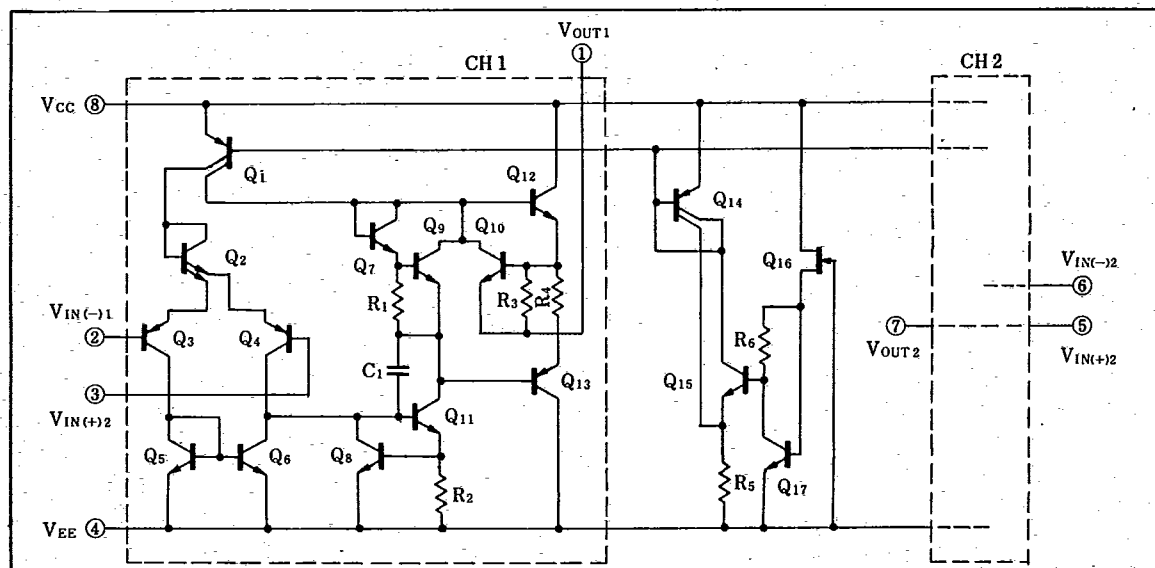
Features

1. Low power dissipation 3.9mW (TYP.)
2. No frequency compensation required
3. Short circuit protected outputs
4. 8-pin dual-in-line package (IR9022)
8-pin small-outline package (IR9022N)

Pin Connections



Equivalent Circuit



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Absolute Maximum Ratings

(Ta=25°C)

Parameter	Symbol	Condition		Rating	Unit
Supply voltage	$V_{CC}-V_{EE}$			36	V
Differential input voltage	V_{ID}			± 30	V
In-phase input voltage	V_{ICM}			± 15	V
Power dissipation	P_D	$T_a \leq 25^{\circ}C$	IR9022	500	mW
			IR9022N	500	
P_D derating ratio	$\Delta P_D/^{\circ}C$	$T_a > 25^{\circ}C$	IR9022	5	mW/ $^{\circ}C$
			IR9022N	4	
Operating temperature	T_{opr}			$-20 \sim +70$	$^{\circ}C$
Storage temperature	T_{stg}		IR9022	$-40 \sim +125$	$^{\circ}C$
			IR9022N	$-55 \sim +150$	

Electrical Characteristics

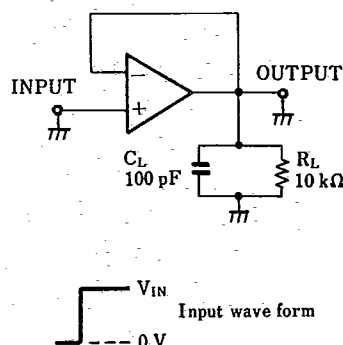
(V_{CC}=15V, V_{EE}=-15V, Ta=25°C)

Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit
Input offset voltage	V_{IO}	$R_S \leq 10\text{k}\Omega$		1	5	mV
Input offset current	I_{IO}			15	80	nA
Input bias current	I_B			100	250	nA
In-phase input voltage	V_{ICM}		± 12	± 13		V
Major amplitude voltage gain	A_V	$R_L \geq 10\text{k}\Omega$, $V_{OUT} = \pm 10\text{V}$	60	80		dB
Maximum output voltage	V_{OM}	$R_L = 10\text{k}\Omega$	20	26		V
Common signal rejection ratio	CMR	$R_S \leq 10\text{k}\Omega$	60	72		dB
Supply voltage rejection ratio	SVR	$R_S \leq 10\text{k}\Omega$		30	200	$\mu\text{V/V}$
Supply current	I_{CC}			130	250	μA
Power dissipation	P_D			3.9	7.5	mW
Output short circuit current	I_{OS}			± 6		mA
Input conversion noise voltage	V_{NI}	$A_V = 20\text{dB}$, $f = 1\text{kHz}$, $B = 1\text{Hz}$		50		$\text{nV}/\sqrt{\text{Hz}}$
Slew rate	SR	$V_{IN} = 10\text{V}$, $R_L = 10\text{k}\Omega$, $C_L = 100\text{pF}$		0.5		$\text{V}/\mu\text{s}$
Rise time	t_r	$V_{IN} = 20\text{mV}$, $R_L = 10\text{k}\Omega$, $C_L = 100\text{pF}$		0.3		μs
Overshoot	OS	$V_{IN} = 20\text{mV}$, $R_L = 10\text{k}\Omega$, $C_L = 100\text{pF}$		5		%

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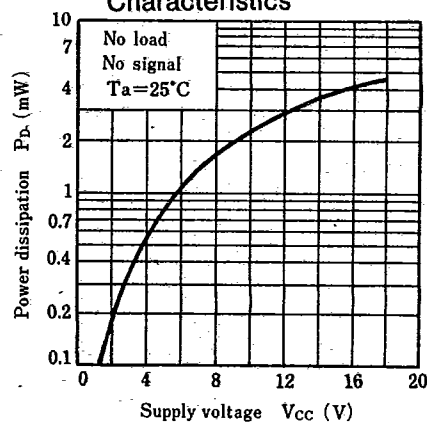
Test Circuit

Overshoot, slew rate, rising time



Electrical Characteristic Curve

Power dissipation—Supply voltage Characteristics



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